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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M4F
Core Size	32-Bit Single-Core
Speed	168MHz
Connectivity	CANbus, FlexIO, I²C, SPI, UART/USART
Peripherals	DMA, LVD, PWM, WDT
Number of I/O	89
Program Memory Size	256KB (256K x 8)
Program Memory Type	FLASH
EEPROM Size	68K x 8
RAM Size	64K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 16x12b; D/A 1x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mke18f256vll16

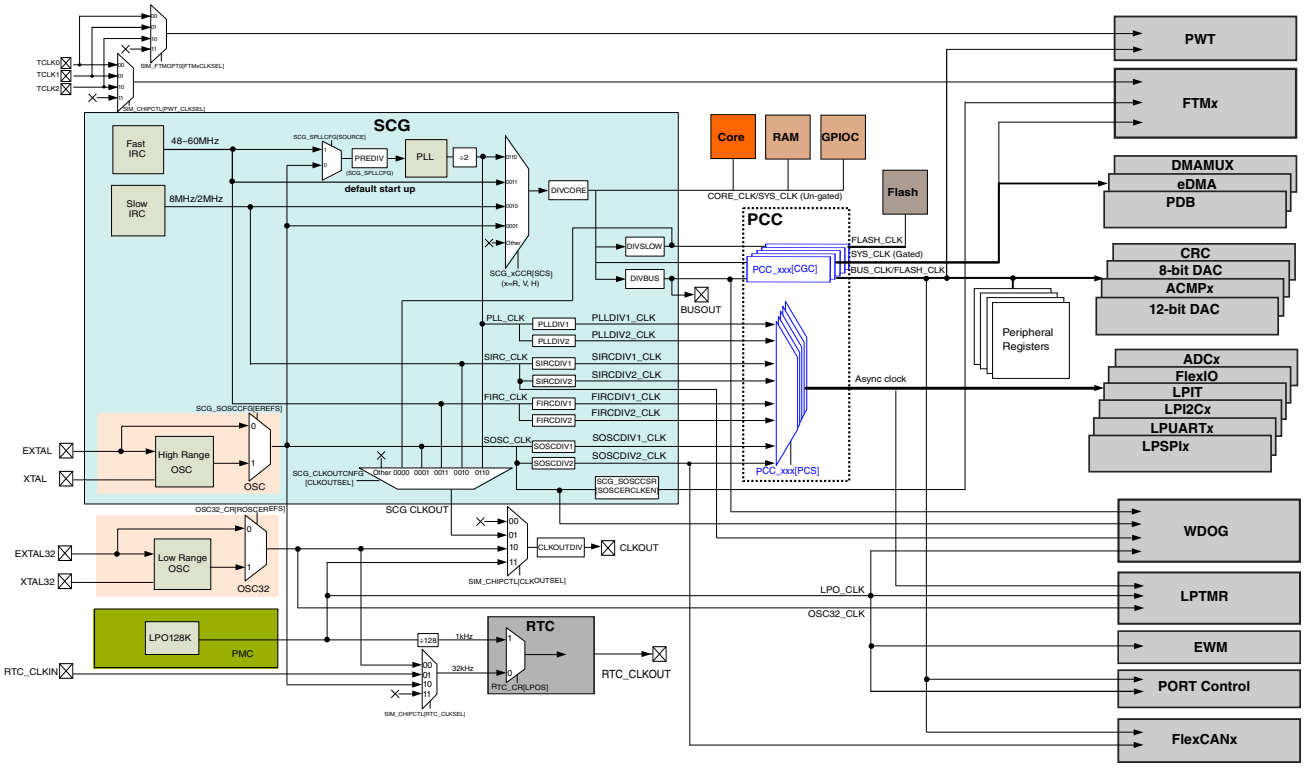


Figure 4. Clocking block diagram

2.1.7 Security

Security state can be enabled via programming flash configure field (0x40e). After enabling device security, the SWD/JTAG port cannot access the memory resources of the MCU.

External interface	Security	Unsecure
SWD/JTAG port	Can't access memory source by SWD/ JTAG interface	the debugger can write to the Flash Mass Erase in Progress field of the MDM-AP Control register to trigger a mass erase (Erase All Blocks) command

2.1.7.1 Flash Access Control (FAC)

The FAC is a native or third-party configurable memory protection scheme optimized to allow end users to utilize software libraries while offering programmable restrictions to these libraries. The flash memory is divided into equal size segments that provide protection to proprietary software libraries. The protection of these

RTC is reset on power-on reset, and a software reset bit in RTC can also initialize all RTC registers.

The RTC module has the following features

- 32-bit seconds counter with roll-over protection and 32-bit alarm
- 16-bit prescaler with compensation that can correct errors between 0.12 ppm and 3906 ppm
- Register write protection with register lock mechanism
- 1 Hz square wave or second pulse output with optional interrupt

2.2.7 LPIT

The Low Power Periodic Interrupt Timer (LPIT) is a multi-channel timer module generating independent pre-trigger and trigger outputs. These timer channels can operate individually or can be chained together. The LPIT can operate in low power modes if configured to do so. The pre-trigger and trigger outputs can be used to trigger other modules on the device.

This device contains one LPIT module with four channels. The LPIT generates periodic trigger events to the DMAMUX.

2.2.8 PDB

The Programmable Delay Block (PDB) provides controllable delays from either an internal or an external trigger, or a programmable interval tick, to the hardware trigger inputs of ADCs and/or generates the interval triggers to DACs, so that the precise timing between ADC conversions and/or DAC updates can be achieved. The PDB can optionally provide pulse outputs (Pulse-Out's) that are used as the sample window in the CMP block.

The PDB module has the following capabilities:

- trigger input sources and one software trigger source
- 1 DAC refresh trigger output, for this device
- configurable PDB channels for ADC hardware trigger
- 1 pulse output, for this device

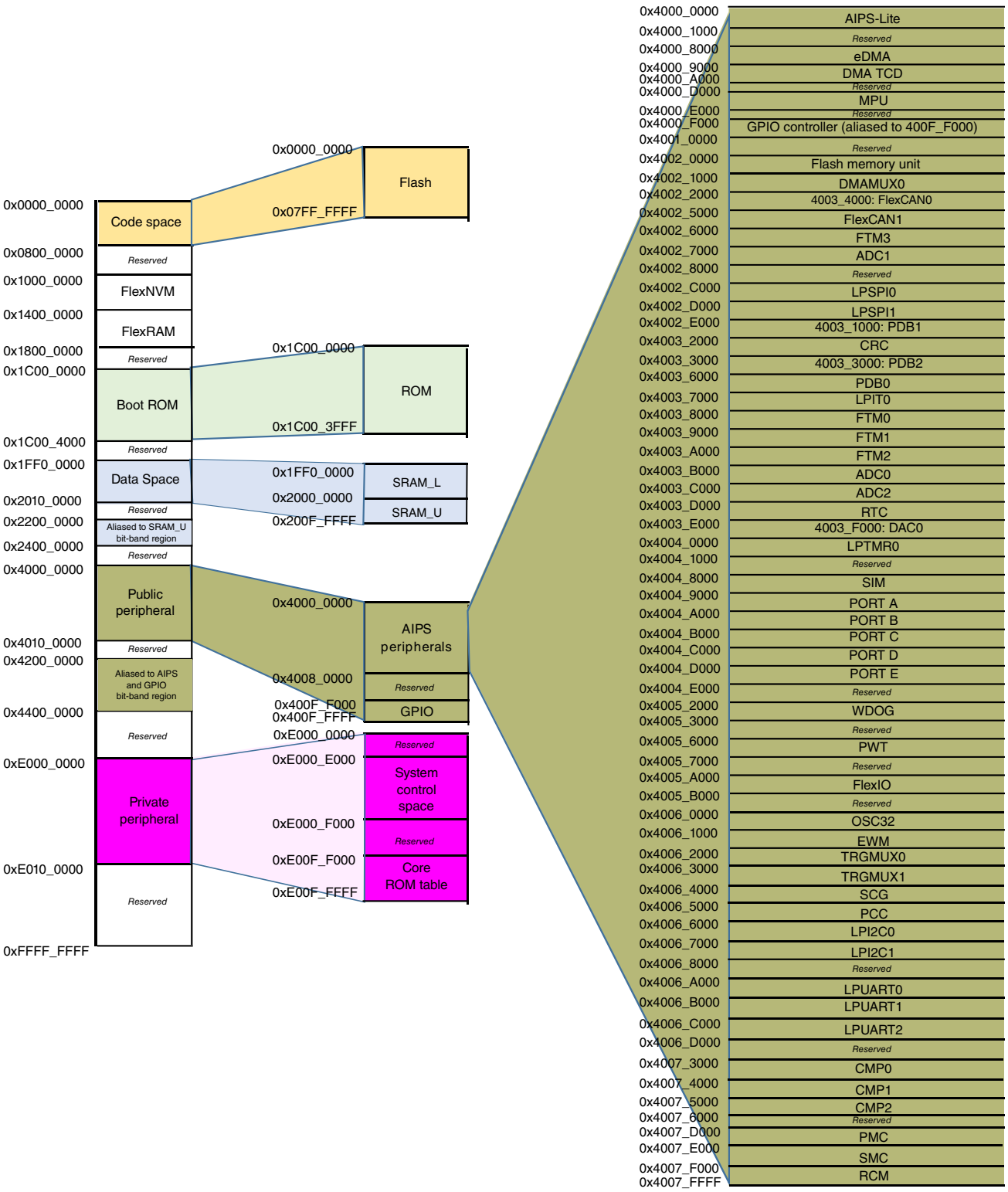


Figure 6. Memory map

4 Pinouts

4.1 KE1xF Signal Multiplexing and Pin Assignments

The following table shows the signals available on each pin and the locations of these pins on the devices supported by this document. The Port Control Module is responsible for selecting which ALT functionality is available on each pin.

NOTE

On this device, there are several special ADC channels which support hardware interleave between multiple ADCs. Taking ADC0_SE4 and ADC1_SE14 channels as an example, these two channels can work independently, but they can also be hardware interleaved. In the hardware interleaved mode, a signal on the pin PTB0 can be sampled by both ADC0 and ADC1. The interleaved mode is enabled by SIM_CHIPCTL[ADC_INTERLEAVE_EN] bits. For more information, see "ADC Hardware Interleaved Channels" in the ADC chapter of Reference Manual.

100 LQFP	64 LQFP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7
—	10	VREFL/ VSS	VREFL/ VSS	VREFL/ VSS							
1	—	PTE16	DISABLED		PTE16			FTM2_CH7		FXIO_D3	TRGMUX_ OUT7
2	—	PTE15	DISABLED		PTE15			FTM2_CH6		FXIO_D2	TRGMUX_ OUT6
3	1	PTD1	ADC2_SE1	ADC2_SE1	PTD1	FTM0_CH3	LPSPI1_SIN	FTM2_CH1		FXIO_D1	TRGMUX_ OUT2
4	2	PTD0	ADC2_SE0	ADC2_SE0	PTD0	FTM0_CH2	LPSPI1_SCK	FTM2_CH0		FXIO_D0	TRGMUX_ OUT1
5	3	PTE11	ADC2_SE13	ADC2_SE13	PTE11	PWT_IN1	LPTMR0_ ALT1	FTM2_CH5		FXIO_D5	TRGMUX_ OUT5
6	4	PTE10	ADC2_SE12	ADC2_SE12	PTE10	CLKOUT		FTM2_CH4		FXIO_D4	TRGMUX_ OUT4
7	—	PTE13	DISABLED		PTE13			FTM2_FLT0			
8	5	PTE5	DISABLED		PTE5	TCLK2	FTM2_QD_ PHA	FTM2_CH3	CAN0_TX	FXIO_D7	EWM_IN
9	6	PTE4	DISABLED		PTE4	BUSOUT	FTM2_QD_ PHB	FTM2_CH2	CAN0_RX	FXIO_D6	EWM_OUT_b

100 LQFP	64 LQFP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7
10	7	VDD	VDD	VDD							
11	8	VDDA	VDDA	VDDA							
12	9	VREFH	VREFH	VREFH							
13	—	VREFL	VREFL	VREFL							
14	—	VSS	VSS	VSS							
15	11	PTB7	EXTAL	EXTAL	PTB7	LPI2C0_SCL					
16	12	PTB6	XTAL	XTAL	PTB6	LPI2C0_SDA					
17	—	PTE14	ACMP2_IN3	ACMP2_IN3	PTE14	FTM0_FLT1		FTM2_FLT1			
18	13	PTE3	DISABLED		PTE3	FTM0_FLT0	LPUART2_ RTS	FTM2_FLT0		TRGMUX_IN6	ACMP2_OUT
19	—	PTE12	DISABLED		PTE12	FTM0_FLT3	LPUART2_TX				
20	—	PTD17	DISABLED		PTD17	FTM0_FLT2	LPUART2_RX				
21	14	PTD16	ACMP2_IN0	ACMP2_IN0	PTD16	FTM0_CH1					
22	15	PTD15	ACMP2_IN1	ACMP2_IN1	PTD15	FTM0_CH0					
23	16	PTE9	ACMP2_IN2/ DAC0_OUT	ACMP2_IN2/ DAC0_OUT	PTE9	FTM0_CH7	LPUART2_ CTS				
24	—	PTD14	DISABLED		PTD14	FTM2_CH5					CLKOUT
25	—	PTD13	DISABLED		PTD13	FTM2_CH4					RTC_CLKOUT
26	17	PTE8	ACMP0_IN3	ACMP0_IN3	PTE8	FTM0_CH6					
27	18	PTB5	DISABLED		PTB5	FTM0_CH5	LPSPI0_PCS1			TRGMUX_IN0	ACMP1_OUT
28	19	PTB4	ACMP1_IN2	ACMP1_IN2	PTB4	FTM0_CH4	LPSPI0_SOUT			TRGMUX_IN1	
29	20	PTC3	ADC0_SE11/ ACMP0_IN4/ EXTAL32	ADC0_SE11/ ACMP0_IN4/ EXTAL32	PTC3	FTM0_CH3	CAN0_TX				
30	21	PTC2	ADC0_SE10/ ACMP0_IN5/ XTAL32	ADC0_SE10/ ACMP0_IN5/ XTAL32	PTC2	FTM0_CH2	CAN0_RX				
31	22	PTD7	DISABLED		PTD7	LPUART2_TX		FTM2_FLT3			
32	23	PTD6	DISABLED		PTD6	LPUART2_RX		FTM2_FLT2			
33	24	PTD5	DISABLED		PTD5	FTM2_CH3	LPTMR0_ ALT2	FTM2_FLT1	PWT_IN2	TRGMUX_IN7	
34	—	PTD12	DISABLED		PTD12	FTM2_CH2	LPI2C1_HREQ			LPUART2_ RTS	
35	—	PTD11	DISABLED		PTD11	FTM2_CH1	FTM2_QD_ PHA			LPUART2_ CTS	
36	—	PTD10	DISABLED		PTD10	FTM2_CH0	FTM2_QD_ PHB				
37	—	VSS	VSS	VSS							
38	—	VDD	VDD	VDD							
39	25	PTC1	ADC0_SE9/ ACMP1_IN3	ADC0_SE9/ ACMP1_IN3	PTC1	FTM0_CH1				FTM1_CH7	
40	26	PTC0	ADC0_SE8/ ACMP1_IN4	ADC0_SE8/ ACMP1_IN4	PTC0	FTM0_CH0				FTM1_CH6	

100 LQFP	64 LQFP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7
41	—	PTD9	ACMP1_IN5	ACMP1_IN5	PTD9	LPI2C1_SCL		FTM2_FLT3		FTM1_CH5	
42	—	PTD8	DISABLED		PTD8	LPI2C1_SDA		FTM2_FLT2		FTM1_CH4	
43	27	PTC17	ADC0_SE15	ADC0_SE15	PTC17	FTM1_FLT3		LPI2C1_SCLS			
44	28	PTC16	ADC0_SE14	ADC0_SE14	PTC16	FTM1_FLT2		LPI2C1_SDAS			
45	29	PTC15	ADC0_SE13/ ACMP2_IN4	ADC0_SE13/ ACMP2_IN4	PTC15	FTM1_CH3					
46	30	PTC14	ADC0_SE12/ ACMP2_IN5	ADC0_SE12/ ACMP2_IN5	PTC14	FTM1_CH2					
47	31	PTB3	ADC0_SE7	ADC0_SE7	PTB3	FTM1_CH1	LPSPI0_SIN	FTM1_QD_ PHA		TRGMUX_IN2	
48	32	PTB2	ADC0_SE6	ADC0_SE6	PTB2	FTM1_CH0	LPSPI0_SCK	FTM1_QD_ PHB		TRGMUX_IN3	
49	—	PTC13	DISABLED		PTC13	FTM3_CH7	FTM2_CH7				
50	—	PTC12	DISABLED		PTC12	FTM3_CH6	FTM2_CH6				
51	—	PTC11	DISABLED		PTC11	FTM3_CH5					
52	—	PTC10	DISABLED		PTC10	FTM3_CH4					
53	33	PTB1	ADC0_SE5	ADC0_SE5	PTB1	LPUART0_TX	LPSPI0_SOUT	TCLK0			
54	34	PTB0	ADC0_SE4	ADC0_SE4	PTB0	LPUART0_RX	LPSPI0_PCS0	LPTMR0_ ALT3	PWT_IN3		
55	35	PTC9	ADC2_SE15	ADC2_SE15	PTC9	LPUART1_TX	FTM1_FLT1			LPUART0_ RTS	
56	36	PTC8	ADC2_SE14	ADC2_SE14	PTC8	LPUART1_RX	FTM1_FLT0			LPUART0_ CTS	
57	37	PTA7	ADC0_SE3/ ACMP1_IN1	ADC0_SE3/ ACMP1_IN1	PTA7	FTM0_FLT2		RTC_CLKIN		LPUART1_ RTS	
58	38	PTA6	ADC0_SE2/ ACMP1_IN0	ADC0_SE2/ ACMP1_IN0	PTA6	FTM0_FLT1	LPSPI1_PCS1			LPUART1_ CTS	
59	39	PTE7	ADC2_SE2/ ACMP2_IN6	ADC2_SE2/ ACMP2_IN6	PTE7	FTM0_CH7	FTM3_FLT0				
60	40	VSS	VSS	VSS							
61	41	VDD	VDD	VDD							
62	—	PTA17	DISABLED		PTA17	FTM0_CH6	FTM3_FLT0	EWM_OUT_b			
63	—	PTB17	ADC2_SE3	ADC2_SE3	PTB17	FTM0_CH5	LPSPI1_PCS3				
64	—	PTB16	ADC1_SE15	ADC1_SE15	PTB16	FTM0_CH4	LPSPI1_SOUT				
65	—	PTB15	ADC1_SE14	ADC1_SE14	PTB15	FTM0_CH3	LPSPI1_SIN				
66	—	PTB14	ADC1_SE9	ADC1_SE9	PTB14	FTM0_CH2	LPSPI1_SCK				
67	42	PTB13	ADC1_SE8	ADC1_SE8	PTB13	FTM0_CH1	FTM3_FLT1				
68	43	PTB12	ADC1_SE7	ADC1_SE7	PTB12	FTM0_CH0	FTM3_FLT2				
69	44	PTD4	ADC1_SE6/ ACMP1_IN6	ADC1_SE6/ ACMP1_IN6	PTD4	FTM0_FLT3	FTM3_FLT3				
70	45	PTD3	NMI_b	ADC1_SE3	PTD3	FTM3_CH5	LPSPI1_PCS0	FXIO_D5		TRGMUX_IN4	NMI_b
71	46	PTD2	ADC1_SE2	ADC1_SE2	PTD2	FTM3_CH4	LPSPI1_SOUT	FXIO_D4		TRGMUX_IN5	
72	47	PTA3	ADC1_SE1	ADC1_SE1	PTA3	FTM3_CH1	LPI2C0_SCL	EWM_IN		LPUART0_TX	

Table 21. LPSPI*n* Signal Descriptions

Chip signal name	Module signal name	Description	I/O
LPSPI*n*_SOUT	SOUT	Serial Data Out	O
LPSPI*n*_SIN	SIN	Serial Data In	I
LPSPI*n*_SCK	SCK	Serial Clock	I/O
LPSPI*n*_PCS[3:0]	PCS[3:0]	Peripheral Chip Select 0-3	I/O

Table 22. LPI2C*n* Signal Descriptions

Chip signal name	Module signal name	Description	I/O
LPI2C*n*_SCL	SCL	Bidirectional serial clock line of the I2C system.	I/O
LPI2C*n*_SDA	SDA	Bidirectional serial data line of the I2C system.	I/O
LPI2C*n*_HREQ	HREQ	Host request, can initiate an LPI2C master transfer if asserted and the I2C bus is idle.	I
LPI2C*n*_SCLS	SCLS	Secondary I2C clock line.	I/O
LPI2C*n*_SDAS	SDAS	Secondary I2C data line.	I/O

Table 23. LPUART*n* Signal Descriptions

Chip signal name	Module signal name	Description	I/O
LPUART*n*_TX	LPUART_TX	Transmit data	O
LPUART*n*_RX	LPUART_RX	Receive data	I
LPUART*n*_CTS	LPUART_CTS	Clear to send	I
LPUART*n*_RTS	LPUART_RTS	Request to send	O

Table 24. FlexIO Signal Descriptions

Chip signal name	Module signal name	Description	I/O
FXIO_D[7:0]	FXIO_D[7:0]	Bidirectional FlexIO Shifter and Timer pin inputs/outputs	I/O

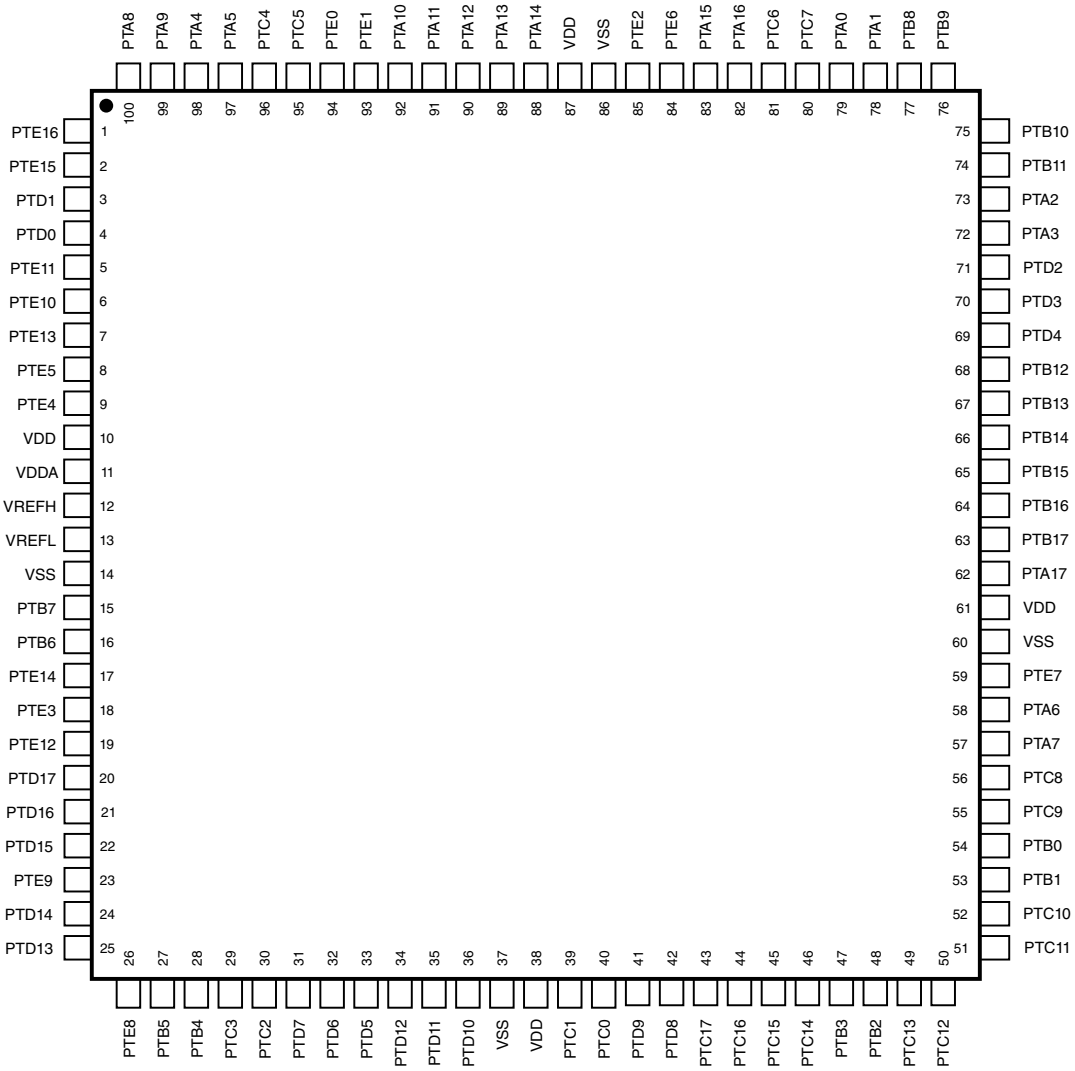


Figure 7. 100 LQFP Pinout Diagram

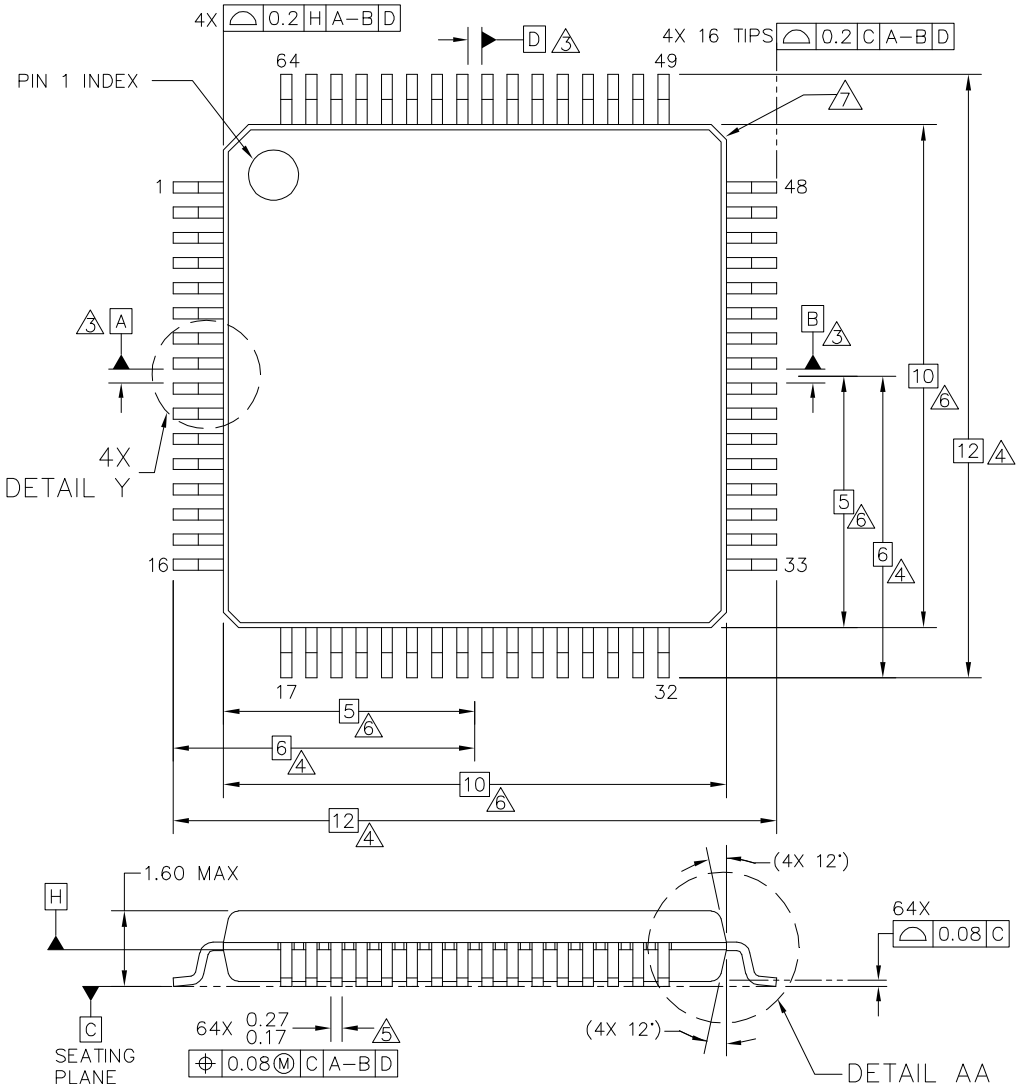
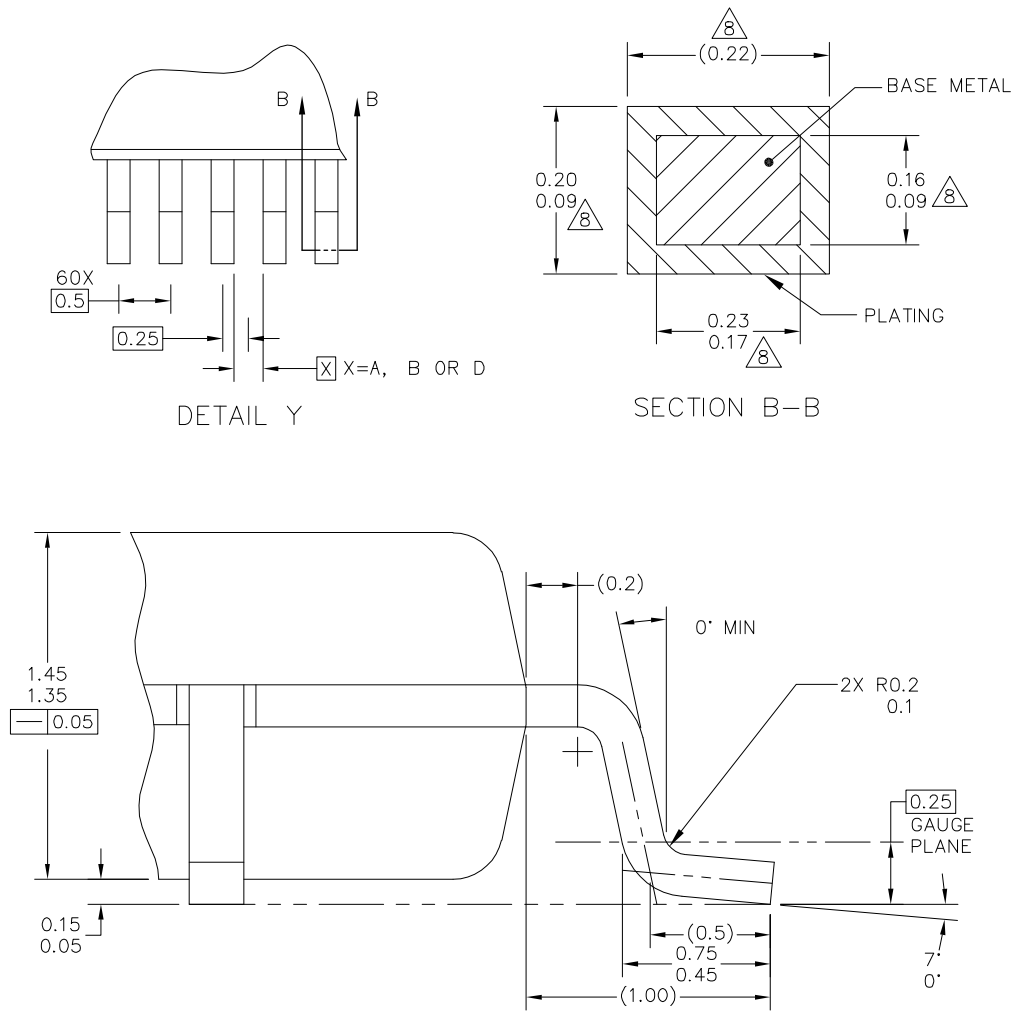


Figure 11. 64-pin LQFP package dimensions 1



NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M–1994.
3. DATUMS A, B AND D TO BE DETERMINED AT DATUM PLANE H.
4. DIMENSIONS TO BE DETERMINED AT SEATING PLANE C.
5. THIS DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED THE UPPER LIMIT BY MORE THAN 0.08 MM AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD SHALL NOT BE LESS THAN 0.07 MM.
6. THIS DIMENSION DOES NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25 MM PER SIDE. THIS DIMENSION IS MAXIMUM PLASTIC BODY SIZE DIMENSION INCLUDING MOLD MISMATCH.
7. EXACT SHAPE OF EACH CORNER IS OPTIONAL.
8. THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.1 MM AND 0.25 MM FROM THE LEAD TIP.

Figure 12. 64-pin LQFP package dimensions 2

5 Electrical characteristics

5.1 Terminology and guidelines

5.1.1 Definitions

Key terms are defined in the following table:

Term	Definition
Rating	A minimum or maximum value of a technical characteristic that, if exceeded, may cause permanent chip failure: • *Operating ratings* apply during operation of the chip. • *Handling ratings* apply when the chip is not powered. **NOTE:** The likelihood of permanent chip failure increases rapidly as soon as a characteristic begins to exceed one of its operating ratings.
Operating requirement	A specified value or range of values for a technical characteristic that you must guarantee during operation to avoid incorrect operation and possibly decreasing the useful life of the chip
Operating behavior	A specified value or range of values for a technical characteristic that are guaranteed during operation if you meet the operating requirements and any other specified conditions
Typical value	A specified value for a technical characteristic that: • Lies within the range of values specified by the operating behavior • Is representative of that characteristic during operation when you meet the typical-value conditions or other specified conditions **NOTE:** Typical values are provided as design guidelines and are neither tested nor guaranteed.

5.1.2 Examples

Operating rating:

Symbol	Description	Min.	Max.	Unit
V_{DD}	1.0 V core supply voltage	–0.3	1.2	V

Operating requirement:

Symbol	Description	Min.	Max.	Unit
V_{DD}	1.0 V core supply voltage	0.9	1.1	V

Operating behavior that includes a *typical value*:

Symbol	Description	Min.	Typ.	Max.	Unit
I_{WP}	Digital I/O weak pullup/pulldown current	10	70	130	µA

5.1.3 Typical-value conditions

Typical values assume you meet the following conditions (or other conditions as specified):

Symbol	Description	Value	Unit
T_A	Ambient temperature	25	°C
V_{DD}	Supply voltage	5.0	V

Table 28. DC electrical specifications (continued)

Symbol	Parameter	Value			Unit	Notes
		Min	Typ	Max		
I_{OLT}	Output low current total for all ports	—	—	100	mA	
I_{IN}	Input leakage current (per pin) for full temperature range @ V_{DD} = 3.3 V					8, 7
	All pins other than high drive port pins	—	0.002	0.5	µA	
	High drive port pins	—	0.004	0.5	µA	
	Input leakage current (per pin) for full temperature range @ V_{DD} = 5.5 V					
	All pins other than high drive port pins	—	0.005	0.5	µA	
	High drive port pins	—	0.010	0.5	µA	
R_{PU}	Internal pull-up resistors @ V_{DD} = 3.3 V	20	—	65	kΩ	9
	@ V_{DD} = 5.0 V	20	—	50	kΩ	
R_{PD}	Internal pull-down resistors @ V_{DD} = 3.3 V	20	—	65	kΩ	10
	@ V_{DD} = 5.0 V	20	—	50	kΩ	

1. Max power supply ramp rate is 500 V/ms.
2. The value given is measured at high drive strength mode. For value at low drive strength mode see the Ioh_5 value given above.
3. The 20 mA I/O pin is capable of switching a 50 pF load at up to 40 MHz.
4. The value given is measured at high drive strength mode. For value at low drive strength mode see the Iol_5 value given above.
5. Refers to the current that leaks into the core when the pad is in Hi-Z (Off state).
6. Maximum pin leakage current at the ambient temperature upper limit.
7. PTD0, PTD1, PTD15, PTD16, PTB4, PTB5, PTE0 and PTE1 I/O have both high drive and normal drive capability selected by the associated Portx_PCRn[DSE] control bit. All other GPIOs are normal drive only.
8. Refers to the pin leakage on the GPIOs when they are OFF.
9. Measured at V_{DD} supply voltage = V_{DD} min and input V = V_{SS}
10. Measured at V_{DD} supply voltage = V_{DD} min and input V = V_{DD}

Table 34. Device clock specifications (continued)

Symbol	Description	Min.	Max.	Unit	Notes
f_{FLASH}	Flash clock	—	25	MHz	
Normal RUN mode					
f_{SYS}	System and core clock	—	120	MHz	
f_{BUS}	Bus clock	—	60	MHz	
f_{FLASH}	Flash clock	—	25	MHz	
f_{LPTMR}	LPTMR clock	—	50	MHz	
VLPR / VLPW mode[1]					
f_{SYS}	System and core clock	—	4	MHz	
f_{BUS}	Bus clock	—	4	MHz	
f_{FLASH}	Flash clock	—	1	MHz	
f_{ERCLK}	External reference clock	—	16	MHz	
f_{LPTMR}	LPTMR clock	—	13	MHz	
$f_{FlexCAN}$	FlexCAN clock	—	4	MHz	

1. The frequency limitations in VLPR / VLPW mode here override any frequency specification listed in the timing specification for any other module.

5.3.2.2 AC electrical characteristics

Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and rise and fall times are measured at the 20% and 80% points, as shown in the following figure.

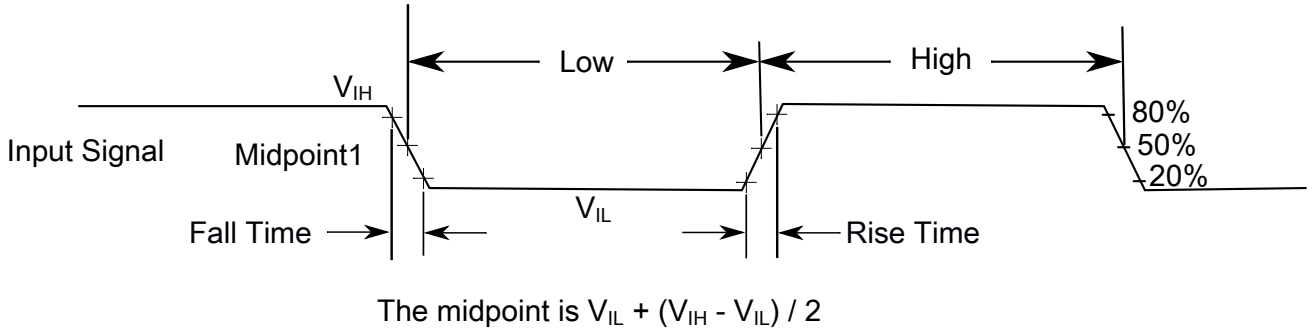


Figure 16. Input signal measurement reference

All digital I/O switching characteristics, unless otherwise specified, assume that the output pins have the following characteristics.

- C_L=30 pF loads
- Normal drive strength

Table 48. PLL electrical specifications (continued)

Symbol	Parameter	Min.	Typ.	Max.	Unit
	VCO @ 150 MHz (F_{pll_ref} = 12 MHz, VDIV multiplier = 25, PRDIV divide = 2)	—	2.8	—	mA
	VCO @ 300 MHz (F_{pll_ref} = 12 MHz, VDIV multiplier = 50, PRDIV divide = 2)	—	3.6	—	mA
J_{cyc_pll}	PLL Period Jitter (RMS)[2]				
	at F_{vco} 180 MHz	—	120	—	ps
	at F_{vco} 360 MHz	—	75	—	ps
J_{acc_pll}	PLL accumulated jitter over 1µs (RMS)[2]				
	at F_{vco} 180 MHz	—	1350	—	ps
	at F_{vco} 360 MHz	—	600	—	ps
D_{unl}	Lock exit frequency tolerance	± 4.47	—	± 5.97	%
T_{pll_lock}	Lock detector detection time[3]	—	—	100×10^{-6} + 1075(1/F_{pll_ref})	s

1. Excludes any oscillator currents that are also consuming power while PLL is in operation.
2. This specification was obtained using a NXP developed PCB. PLL jitter is dependent on the noise characteristics of each PCB and results will vary
3. This specification applies to any time the PLL VCO divider or reference divider is changed, or changing from PLL disabled (BLPE, BLPI) to PLL enabled (PBE, PEE). If a crystal/resonator is being used as the reference, thisspecification assumes it is already running.

5.4.3 Memories and memory interfaces

5.4.3.1 Flash memory module (FTFE) electrical specifications

This section describes the electrical characteristics of the flash memory module (FTFE).

5.4.3.1.1 Flash timing specifications — program and erase

The following specifications represent the amount of time the internal charge pumps are active and do not include command overhead.

Table 49. NVM program/erase timing specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
t_{hvpgm8}	Program Phrase high-voltage time	—	7.5	18	µs	
$t_{hversscr}$	Erase Flash Sector high-voltage time	—	13	113	ms	1
$t_{hversblk64k}$	Erase Flash Block high-voltage time for 64 KB	—	52	452	ms	1
$t_{hversblk512k}$	Erase Flash Block high-voltage time for 512 KB	—	416	3616	ms	1

1. Maximum time based on expectations at cycling end-of-life.

5.4.3.1.2 Flash timing specifications — commands

Table 50. Flash command timing specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	Read 1s Block execution time					
$t_{rd1blk64k}$	• 64 KB data flash	—	—	0.5	ms	
$t_{rd1blk512k}$	• 512 KB program flash	—	—	1.8	ms	
$t_{rd1sec2k}$	Read 1s Section execution time (2 KB flash)	—	—	75	µs	1
$t_{rd1sec4k}$	Read 1s Section execution time (4 KB flash)	—	—	100	µs	1
t_{pgmchk}	Program Check execution time	—	—	95	µs	1
t_{rdrsrc}	Read Resource execution time	—	—	40	µs	1
t_{pgm8}	Program Phrase execution time	—	90	150	µs	
	Erase Flash Block execution time					2
$t_{ersblk64k}$	• 64 KB data flash	—	55	475	ms	
$t_{ersblk512k}$	• 512 KB program flash	—	435	3700	ms	
t_{ersscr}	Erase Flash Sector execution time	—	15	115	ms	2
$t_{pgmsec1k}$	Program Section execution time (1KB flash)	—	5	—	ms	
t_{rd1all}	Read 1s All Blocks execution time	—	—	2.2	ms	
t_{rdonce}	Read Once execution time	—	—	30	µs	1
$t_{pgmonce}$	Program Once execution time	—	90	—	µs	
t_{ersall}	Erase All Blocks execution time	—	500	4200	ms	2
t_{vfykey}	Verify Backdoor Access Key execution time	—	—	30	µs	1
$t_{ersallu}$	Erase All Blocks Unsecure execution time	—	500	4200	ms	2
	Program Partition for EEPROM execution time					
$t_{pgmpart32k}$	• 32 KB EEPROM backup	—	70	—	ms	
$t_{pgmpart64k}$	• 64 KB EEPROM backup	—	71	—	ms	
	Set FlexRAM Function execution time:					
$t_{setramff}$	• Control Code 0xFF	—	70	—	µs	
$t_{setram32k}$	• 32 KB EEPROM backup	—	0.8	1.2	ms	
$t_{setram48k}$	• 48 KB EEPROM backup	—	1.0	1.5	ms	
$t_{setram64k}$	• 64 KB EEPROM backup	—	1.3	1.9	ms	
	Byte-write to FlexRAM execution time:					
$t_{eewr8b32k}$	• 32 KB EEPROM backup	—	385	1700	µs	
$t_{eewr8b48k}$	• 48 KB EEPROM backup	—	430	1850	µs	
$t_{eewr8b64k}$	• 64 KB EEPROM backup	—	475	2000	µs	
	16-bit write to FlexRAM execution time:					

Table continues on the next page...

5.4.7.2 JTAG electricals

Table 62. JTAG limited voltage range electricals

Symbol	Description	Min.	Max.	Unit
	Operating voltage	2.7	3.6	V
J1	TCLK frequency of operation			MHz
	Boundary Scan	0	10	
	JTAG and CJTAG	0	20	
J2	TCLK cycle period	1/J1	—	ns
J3	TCLK clock pulse width			ns
	Boundary Scan	50	—	
	JTAG and CJTAG	25	—	
J4	TCLK rise and fall times	—	3	ns
J5	Boundary scan input data setup time to TCLK rise	20	—	ns
J6	Boundary scan input data hold time after TCLK rise	1	—	ns
J7	TCLK low to boundary scan output data valid	—	25	ns
J8	TCLK low to boundary scan output high-Z	—	25	ns
J9	TMS, TDI input data setup time to TCLK rise	8	—	ns
J10	TMS, TDI input data hold time after TCLK rise	1	—	ns
J11	TCLK low to TDO data valid	—	19	ns
J12	TCLK low to TDO high-Z	—	19	ns
J13	TRST assert time	100	—	ns
J14	TRST setup time (negation) to TCLK high	8	—	ns

Table 63. JTAG full voltage range electricals

Symbol	Description	Min.	Max.	Unit
V_{DDA}	Operating voltage	2.7	5.5	V
J1	TCLK frequency of operation			MHz
	Boundary Scan	0	10	
	JTAG and CJTAG	0	15	
J2	TCLK cycle period	1/J1	—	ns
J3	TCLK clock pulse width			ns
	Boundary Scan	50	—	
	JTAG and CJTAG	33	—	
J4	TCLK rise and fall times	—	3	ns
J5	Boundary scan input data setup time to TCLK rise	20	—	ns
J6	Boundary scan input data hold time after TCLK rise	1.4	—	ns
J7	TCLK low to boundary scan output data valid	—	27	ns
J8	TCLK low to boundary scan output high-Z	—	27	ns

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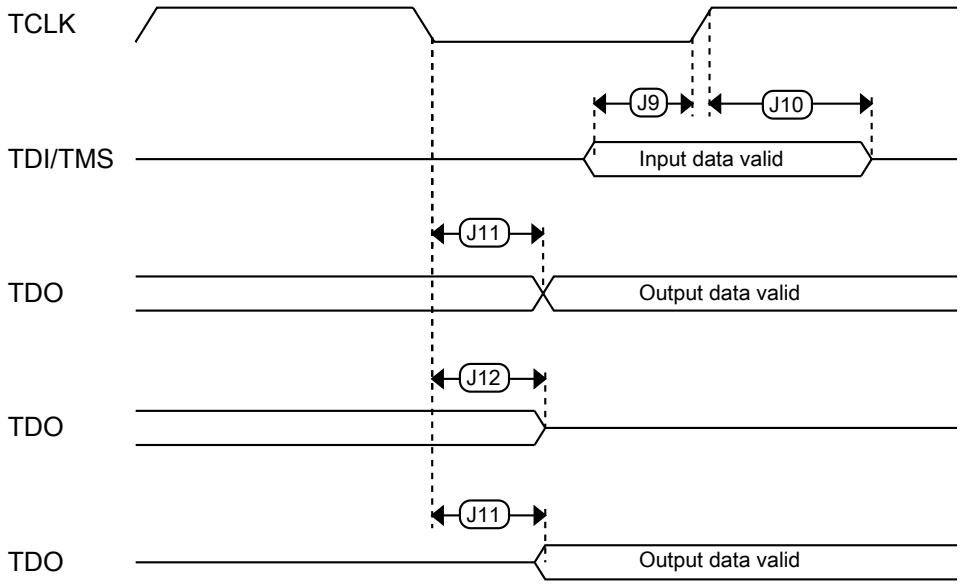

Figure 32. Test Access Port timing

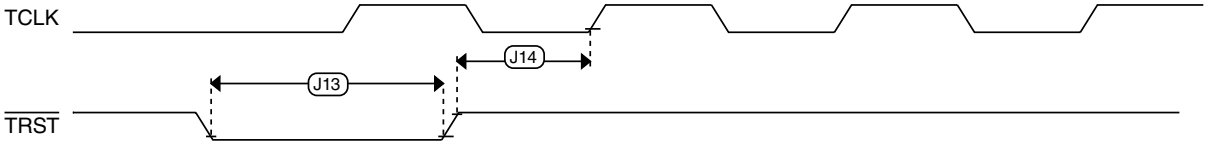

Figure 33. $\overline{\text{TRST}}$ timing

6 Design considerations

6.1 Hardware design considerations

This device contains protective circuitry to guard against damage due to high static voltage or electric fields. However, take normal precautions to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit.

Unused GPIO pins must be left floating (no electrical connections) with the MUX field of the pin's PORTx_PCRn register equal to 0:0:0. This disables the digital input path to the MCU.

6.1.5 Crystal oscillator

When using an external crystal or ceramic resonator as the frequency reference for the MCU clock system, refer to the following table and diagrams.

The feedback resistor, RF, is incorporated internally with the low power oscillators. An external feedback is required when using high gain (HGO=1) mode.

The series resistor, RS, is required in high gain (HGO=1) mode when the crystal or resonator frequency is below 2 MHz. Otherwise, the low power oscillator (HGO=0) must not have any series resistance; and the high frequency, high gain oscillator with a frequency above 2 MHz does not require any series resistance.

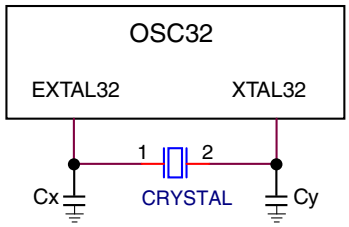

Figure 40. RTC Oscillator (OSC32) module connection – Diagram 1

Table 64. External crystal/resonator connections

Oscillator mode	Oscillator mode
Low frequency (32.768 kHz), high gain	Diagram 3
High frequency (1-32 MHz), low power	Diagram 2
High frequency (1-32 MHz), high gain	Diagram 3

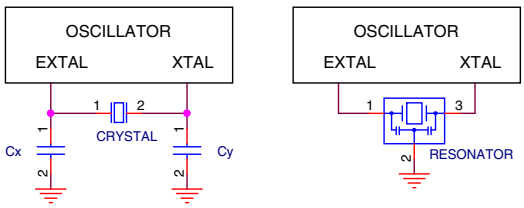

Figure 41. Crystal connection – Diagram 2

7.4 Example

This is an example part number:

MKE18F512VLL16

8 Revision history

The following table provides a revision history for this document.

Table 66. Revision history

Rev. No.	Date	Substantial Changes
2	09/2016	Initial public release.